

HA22040

GaAs MMIC Down Converter for Micro Wave Application

HITACHI

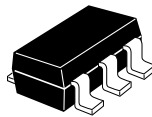
ADE-207-318(Z)
1st. Edition
December 1999

Features

- Suitable for down converter of Micro Wave Application(1.5 GHz)
- Low voltage and low current operation (2.7V, 6mA typ.)
- High conversion gain (10.5 dB typ. @1489MHz)
- Low 3rd-order intercept point (IP3in=-0.5dBm typ, @1489MHz)
- Small surface mount package (MPAK-6)

Outline

MPAK-6



This Device is sensitive to Electro Static Discharge.
An Adequate handling procedure is requested.

CAUTION

This product uses GaAs. Since dust or fume of As, which is a component of GaAs, is highly poisonous to human body, please do not treat them mechanically in the manner which might expose to the Air. And it should never be thrown out with general industrial or domestic wastes.

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Supply voltage	Vdd	5	V
Maximum current	Idd	15	mA
Power dissipation	Pd	100	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	−55 to +125	°C
Operation temperature	Topr	−20 to +70	°C
Maximum input power	Pin max	+15	dBm

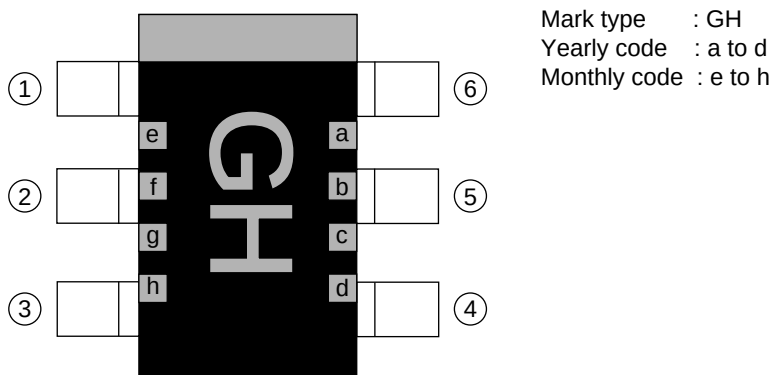
Electrical Characteristics (Ta = 25°C, Vdd = 2.7V)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Quiescent current	Idd	3.5	6	8.5	mA	No signal
Conversion gain	CG	8.5	10.5	12.5	dB	f=1489MHz, fLo=1619MHz, PLo=-12dBm, IF=130MHz, Pin=-30dBm
Noise figure	NF	—	4.5	6	dB	f=1489MHz, fLo=1619MHz, PLo=-12dBm, IF=130MHz

Typical Performance (Ta = 25°C, Vdd = 2.7V)

Item	Symbol	Typ	Unit	Test Conditions
VSWR (input)	VSWR in	1.5	—	f = 1.489 GHz
3rd order intercept point	IP3in	-0.5	dBm	f = 1.489 GHz, fud =1.490 Ghz, Pin=-30dBm, fLo=1.619GHz, PLo=-12dBm

Pin Arrangement



Top View

Yearly code

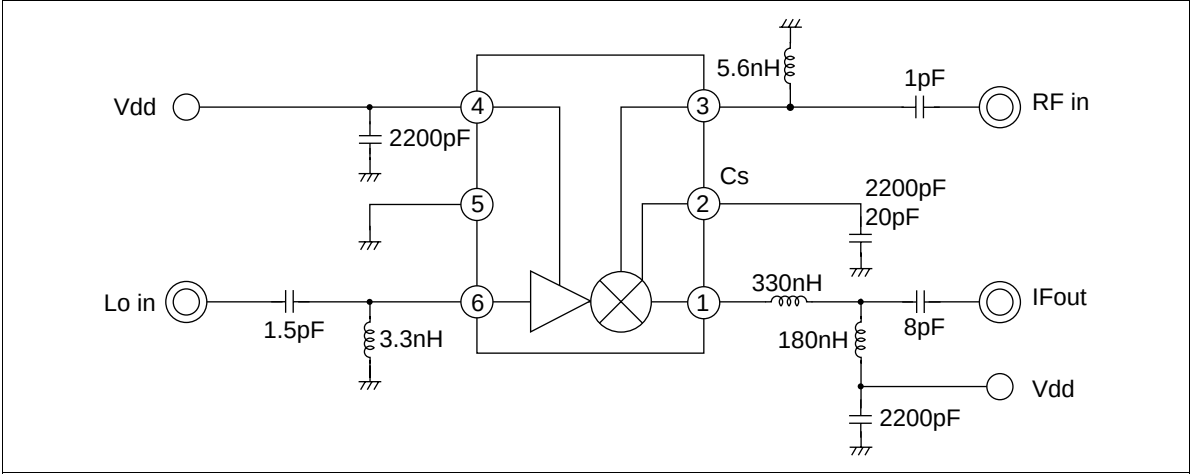
Year	Mark			
	a	b	c	d
1999	■	■	■	■
2000	■	■	■	■
2001	■	■	■	■
2002	■	■	■	■

Monthly code

Month	Mark			
	e	f	g	h
January				
February				
March				
April				
May				
June				
July				
August				
September				
October				
November				
December				

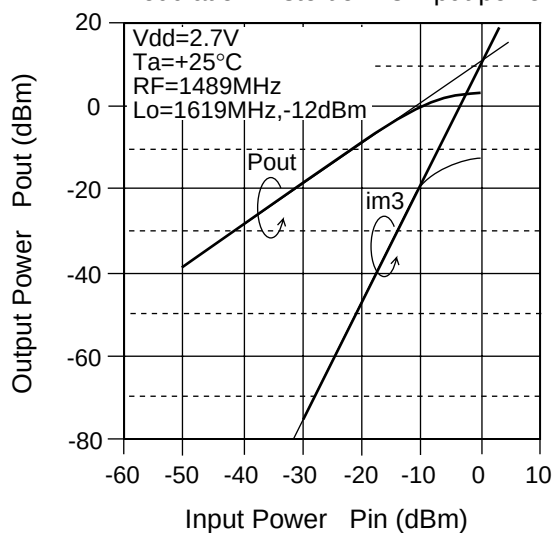
Pin No.	Pin name	Function
1	IF out	IF output
2	Cs	Bypass capacitor
3	RF in	RF input
4	Vdd	Voltage supply
5	GND	Ground
6	Lo in	Local input

Block Diagram

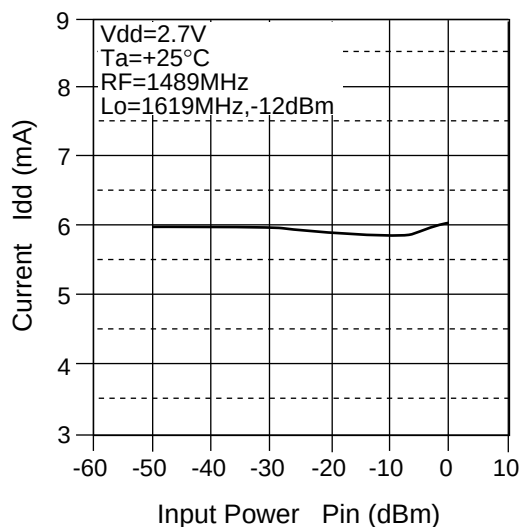


Main Characteristics

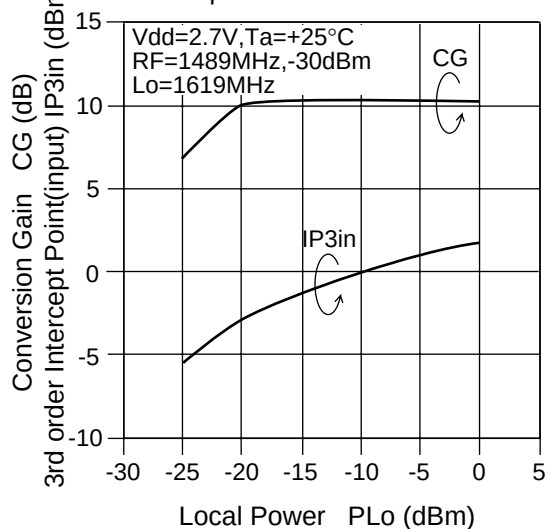
Output power, 3rd Order Inter-modulation Distortion vs. Input power



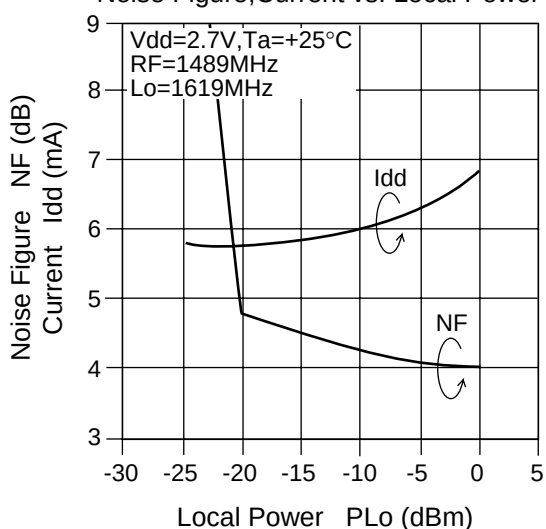
Current vs. Input Power

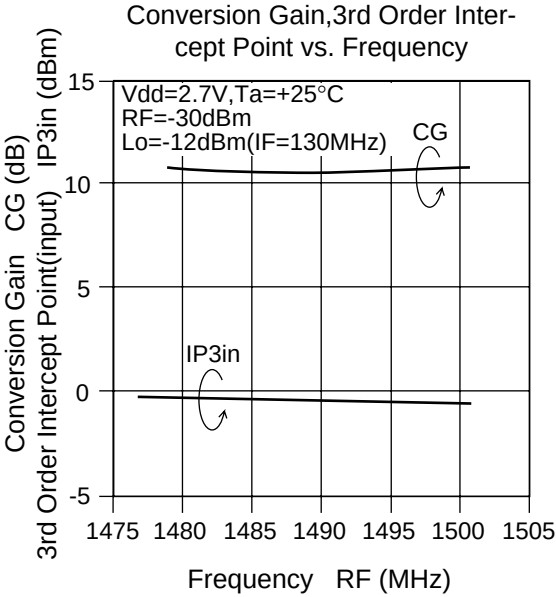
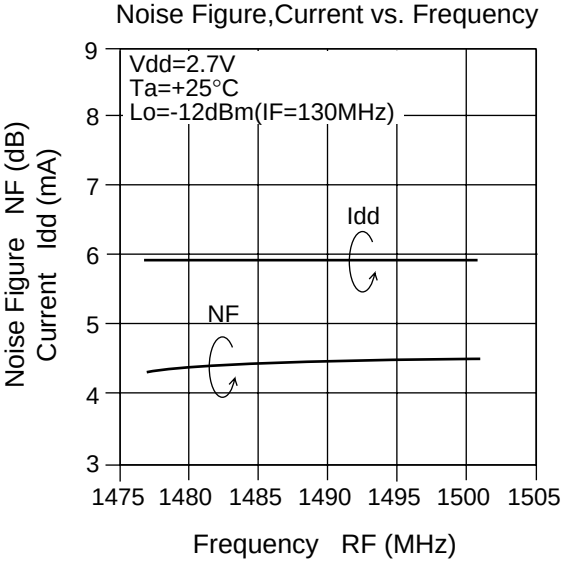
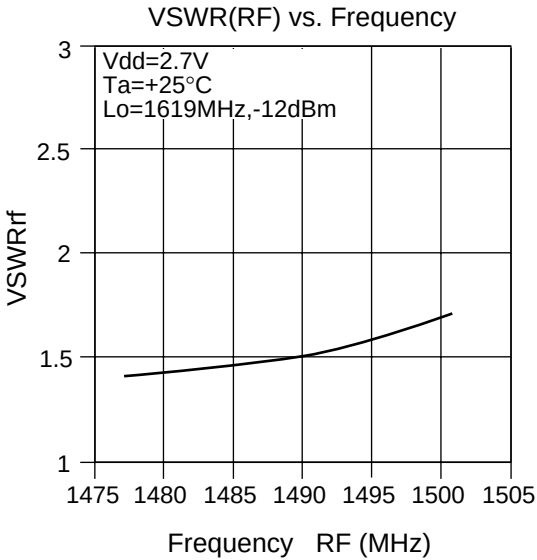
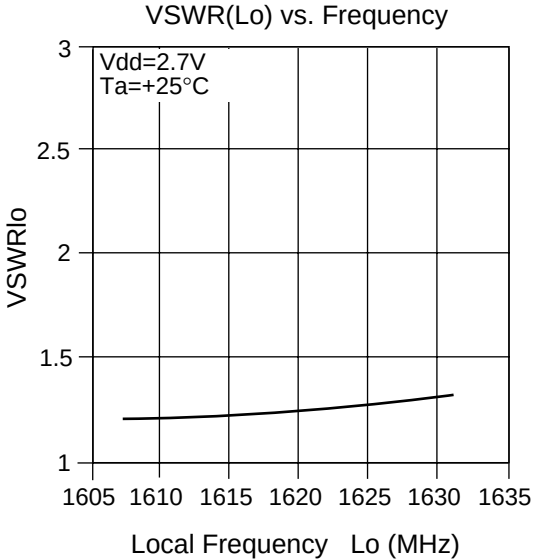


Conversion Gain, 3rd Order intercept Point vs. Local Power

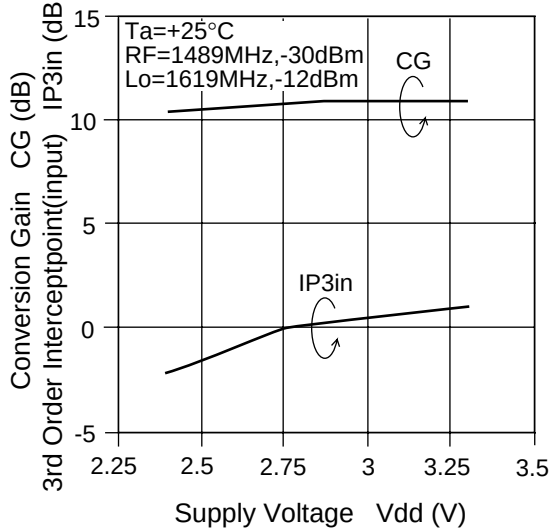


Noise Figure, Current vs. Local Power

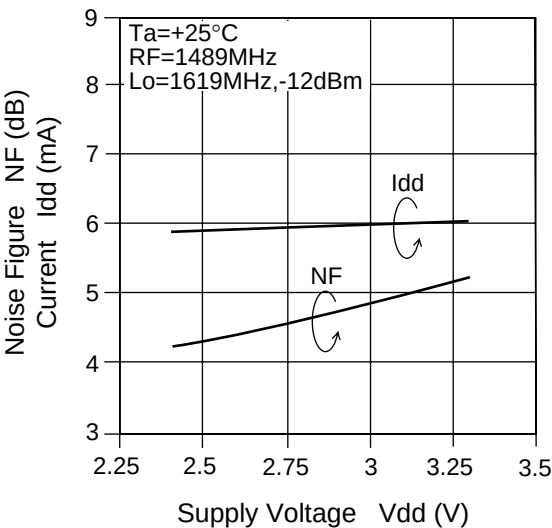




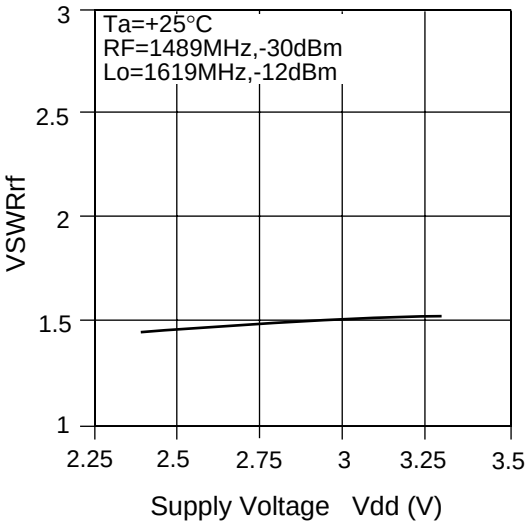
Conversion Gain, 3rd Order Inter-
cept Point vs. Supply Voltage



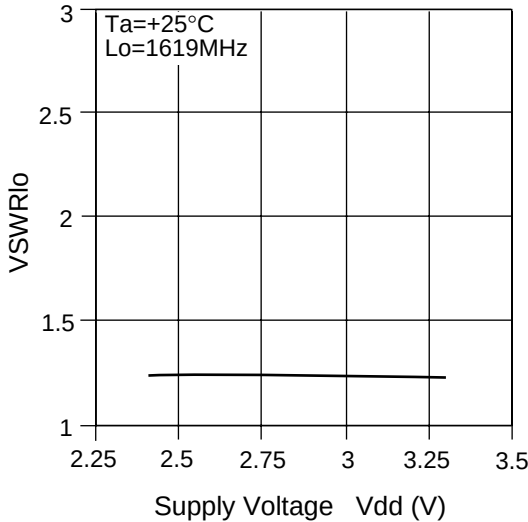
Noise Figure, Current vs. Supply Voltage

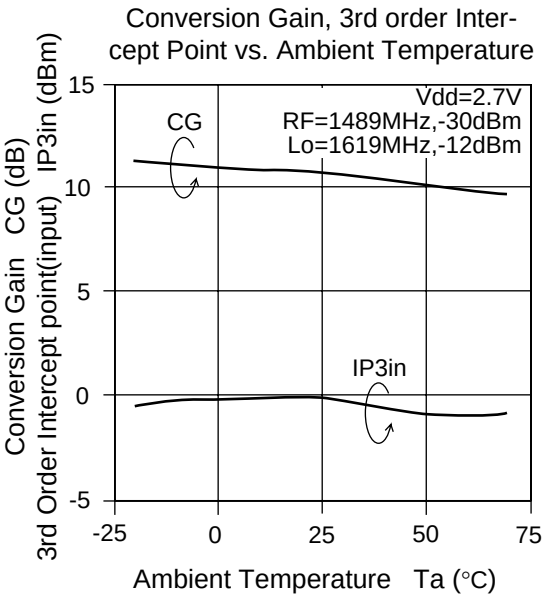
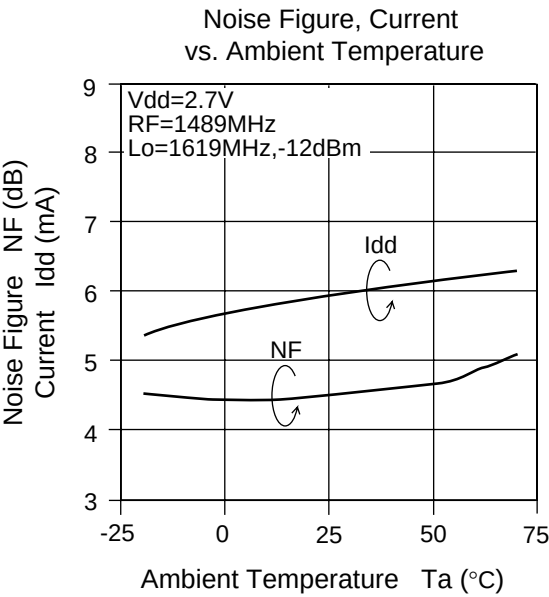
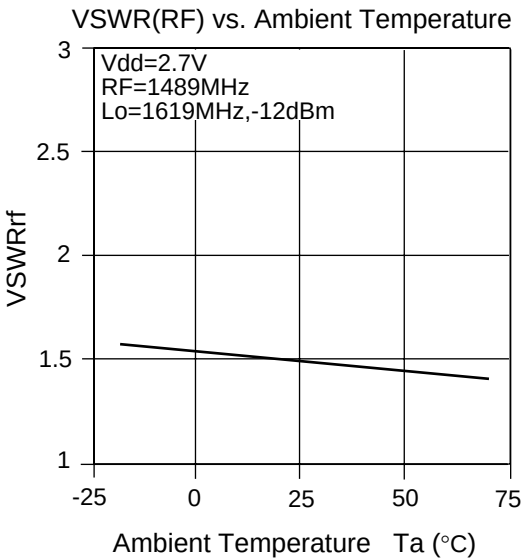
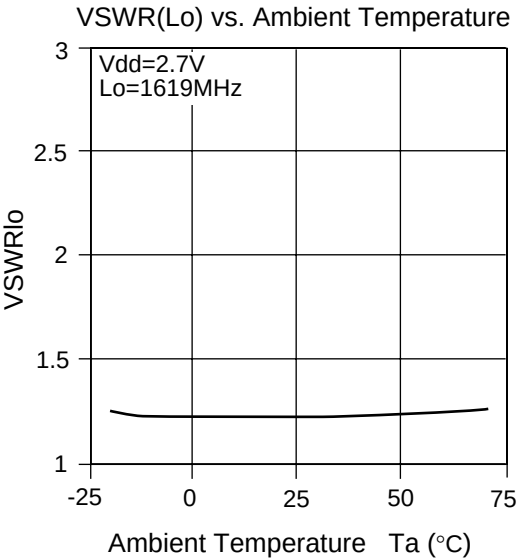


VSWR(RF) vs. Supply Voltage



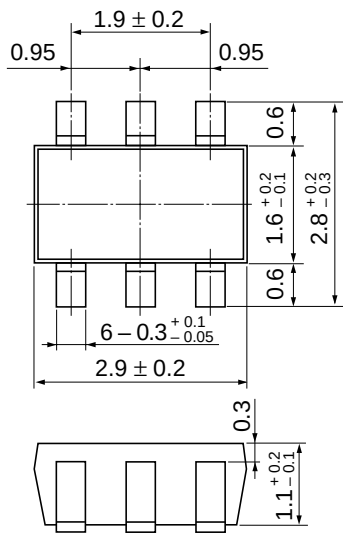
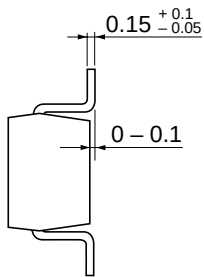
VSWR(Lo) vs. Supply Voltage





Package Dimentions

Unit: mm



Hitachi Code	MPAK-6
JEDEC	—
EIAJ	—
Weight (reference value)	0.014 g

Cautions

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HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.

Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL NorthAmerica : <http://semiconductor.hitachi.com/>
 Europe : <http://www.hitachi-eu.com/hel/ecg>
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For further information write to:

Hitachi Semiconductor
 (America) Inc.
 179 East Tasman Drive,
 San Jose, CA 95134
 Tel: <1> (408) 433-1990
 Fax: <1> (408) 433-0223

Hitachi Europe GmbH
 Electronic components Group
 Dornacher StraÙe 3
 D-85622 Feldkirchen, Munich
 Germany
 Tel: <49> (89) 9 9180-0
 Fax: <49> (89) 9 29 30 00
 Hitachi Europe Ltd.
 Electronic Components Group.
 Whitebrook Park
 Lower Cookham Road
 Maidenhead
 Berkshire SL6 8YA, United Kingdom
 Tel: <44> (1628) 585000
 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd.
 16 Collyer Quay #20-00
 Hitachi Tower
 Singapore 049318
 Tel: 535-2100
 Fax: 535-1533

Hitachi Asia Ltd.
 Taipei Branch Office
 3F, Hung Kuo Building, No.167,
 Tun-Hwa North Road, Taipei (105)
 Tel: <886> (2) 2718-3666
 Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd.
 Group III (Electronic Components)
 7/F., North Tower, World Finance Centre,
 Harbour City, Canton Road, Tsim Sha Tsui,
 Kowloon, Hong Kong
 Tel: <852> (2) 735 9218
 Fax: <852> (2) 730 0281
 Telex: 40815 HITEC HX

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